

# Edges and Excitations for Graphene in the Quantum Hall Regime

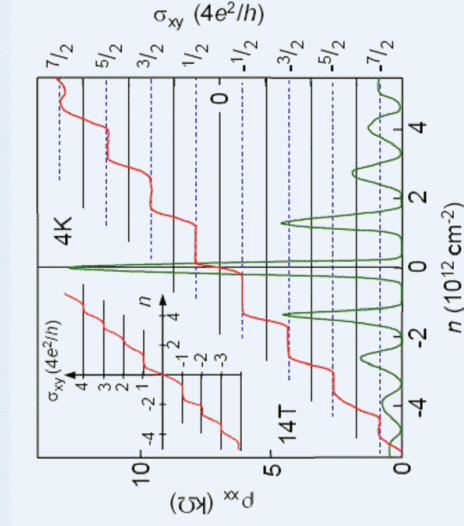
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- I. Introduction: QHE in Graphene; Edge States
- II. Edge States in Graphene: Zigzag and Armchair
- III. Domain Wall at the Edge
- III. Bulk Excitations: Excitons
- V. Summary

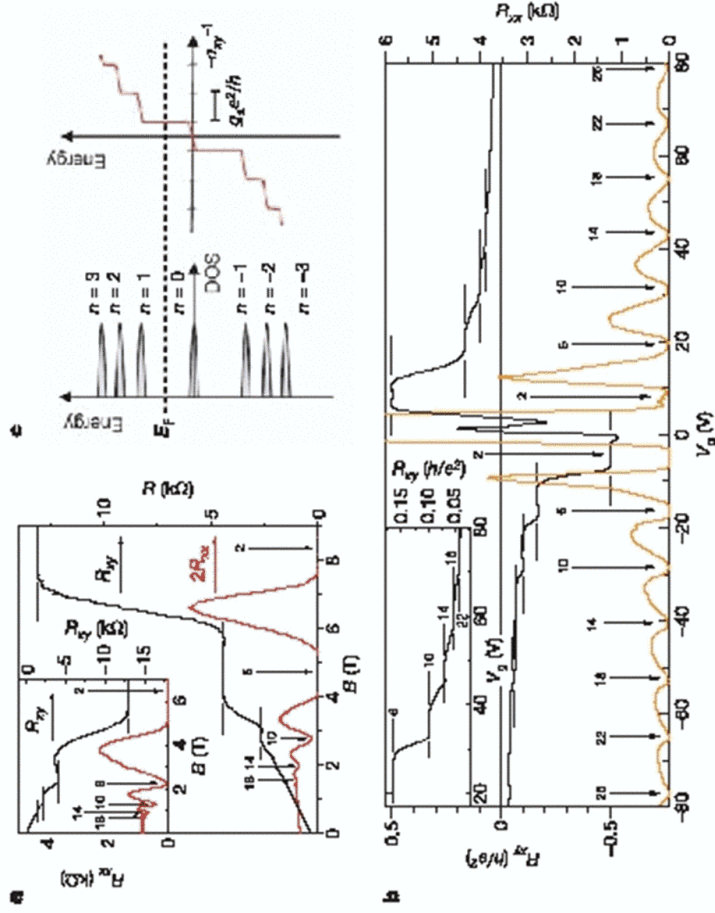
Collaborators: Luis Brey, CSIC, Madrid;  
Drew Iyengar and Jianhui Wang, IU

Funding: NSF

## I. Quantum Hall Effect in Graphene



From Novoselov et al.,  
Nature (2005)



From Zhang et al., Nature (2005)

Electronic states for graphene in a magnetic field

1. k-P approximation: Write  $\psi(\mathbf{r}) = e^{i\mathbf{k}(\cdot)\mathbf{r}}\phi(\mathbf{r})$
2. Peierls substitution:

$$k_\mu \rightarrow -i\partial_\mu \rightarrow -i\partial_\mu - \frac{e}{c}A_\mu$$

3. Choose gauge:

$$A = (-By, 0, 0) \Rightarrow b^\pm = \frac{\ell}{\sqrt{2}}(i\partial_y \pm y\ell^2 - ik_x) \text{ with } \ell = \sqrt{\frac{\hbar c}{eB}}$$

$$\sqrt{3} \frac{a}{\ell} t \begin{pmatrix} 0 & b \\ b^+ & 0 \end{pmatrix} \begin{pmatrix} \phi_A(\vec{r}) \\ \phi_B(\vec{r}) \end{pmatrix} = \varepsilon \begin{pmatrix} \phi_A(\vec{r}) \\ \phi_B(\vec{r}) \end{pmatrix} \quad \tau=+1 \quad K \text{ valley}$$

$$\sqrt{3} \frac{a}{\ell} t \begin{pmatrix} 0 & -b^+ \\ -b & 0 \end{pmatrix} \begin{pmatrix} \phi_A(\vec{r}) \\ \phi_B(\vec{r}) \end{pmatrix} = \varepsilon \begin{pmatrix} \phi_A(\vec{r}) \\ \phi_B(\vec{r}) \end{pmatrix} \quad \tau=-1 \quad K' \text{ valley}$$

Wavefunctions:

$$\Psi(+, n) = e^{ik_x x} \begin{pmatrix} \pm \phi_{n-1}(y - k_x \ell^2) \\ \phi_n(y - k_x \ell^2) \end{pmatrix}$$

$$\Psi(-, n) = e^{ik_x x} \begin{pmatrix} \pm \phi_n(y - k_x \ell^2) \\ \phi_{n-1}(y - k_x \ell^2) \end{pmatrix}$$

$$\Psi(+, \mathbf{0}) = e^{ik_x x} \begin{pmatrix} \mathbf{0} \\ \phi_0 \end{pmatrix}$$

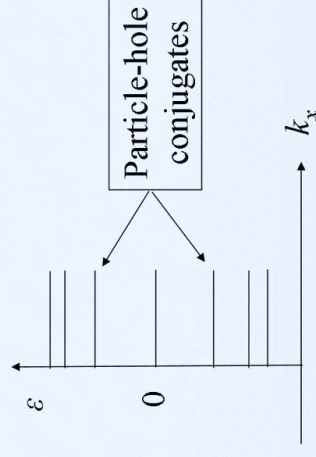
$$\Psi(-, \mathbf{0}) = e^{ik_x x} \begin{pmatrix} \phi_0 \\ \mathbf{0} \end{pmatrix}$$

$\phi_n$  = harmonic oscillator state

Energies:

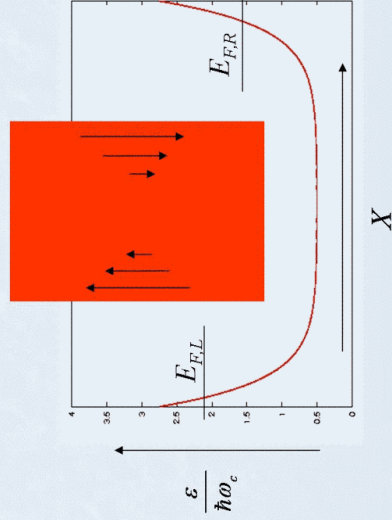
$$\varepsilon(\tau, n) = \pm \sqrt{3 n} \frac{a}{\ell} t$$

With valley and spin indices, each Landau level is 4-fold degenerate



Explanation in terms of edges states:

- Real samples in experiments are very narrow (.1-1 μm) ⇒ edges can have a major impact on transport
- Edge structure can be probed directly via STM at very small length scales. Nothing comparable is possible in standard 2DEG's (GaAs samples, Si MOSFET's)



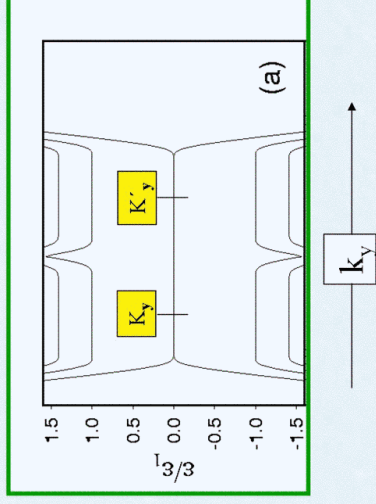
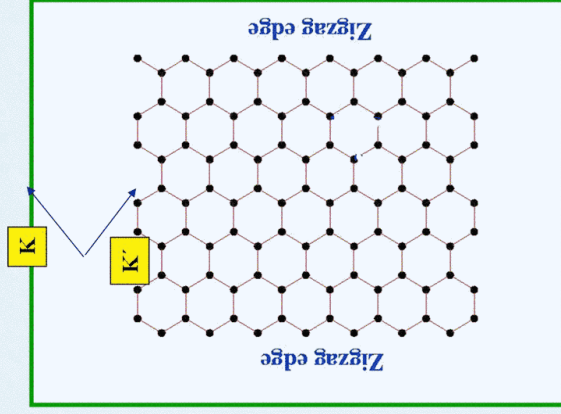
Hall resistance:

$$R_H = V/NI = h/Ne^2$$

with  $N$  the number of edge state pairs crossed by  $E_F$

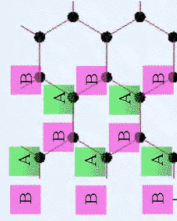
## II. Edge States in Graphene

(1) Tight-binding results, zigzag edge



What happened to the  $n=0$  edge states in the center?

Edge states from Dirac equation:



Boundary condition:  
 $\phi_B(x=0)=0$

Acting on wavefunctions *twice* with Hamiltonian gives scalar equations:

$$\frac{2\gamma^2 a_0^2}{\ell^2} b^\dagger b \varphi_B = \epsilon^2 \varphi_B$$

$$\varphi_A = b \varphi_B / \epsilon$$

$$\frac{2\gamma^2 a_0^2}{\ell^2} b b^\dagger \varphi'_A = \epsilon^2 \varphi'_A$$

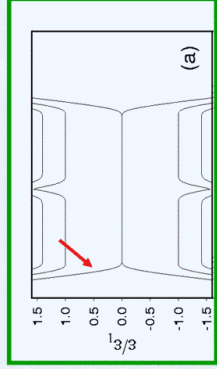
$$\varphi'_B = -b \varphi'_A / \epsilon$$

$$\gamma = \frac{\sqrt{3}}{2} t$$

- For high Landau levels, problem essentially identical to GaAs case
- For  $n=0$ ,  $\mathbf{K}$  and  $\mathbf{K}'$  wavefunctions behave differently

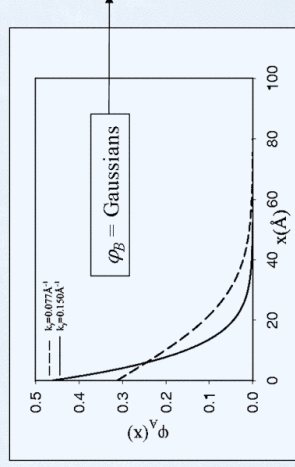
$$\frac{2\gamma^2 a_0^2 b^\dagger b \varphi_B}{\ell^2} = \epsilon^2 \varphi_B$$

$$\varphi_A = b \varphi_B / \epsilon$$

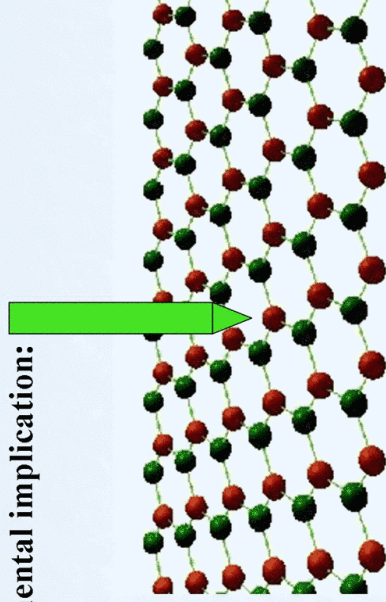


**K-valley: Current Carrying Edge States**

- For  $k_y \ell^2$  not too close to edge,  $\varphi_B$  very similar to a bulk LLL state. Only significant difference is at  $x=0$ .
- Since  $b$  annihilates a LLL state,  $\varphi_A$  strongly localized near  $x=0$ !
- When  $k_y \ell^2$  close to edge, tunneling between A and B becomes significant and hole-like and particle-like states disperse.



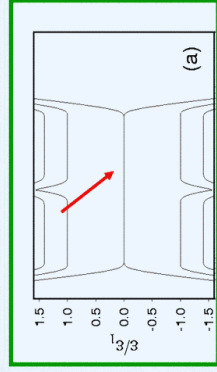
**Possible experimental implication:**



May be able to observe oscillations when injecting electrons with an STM tip near a zigzag edge.  
Oscillation period depends on distance from edge.

$$\frac{2\gamma^2 a_0^2}{\ell^2} b b^\dagger \varphi'_A = \varepsilon^2 \varphi'_A$$

$$\varphi'_B = -b \varphi'_A / \varepsilon$$

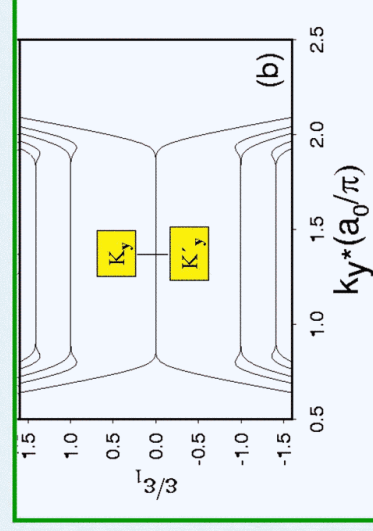
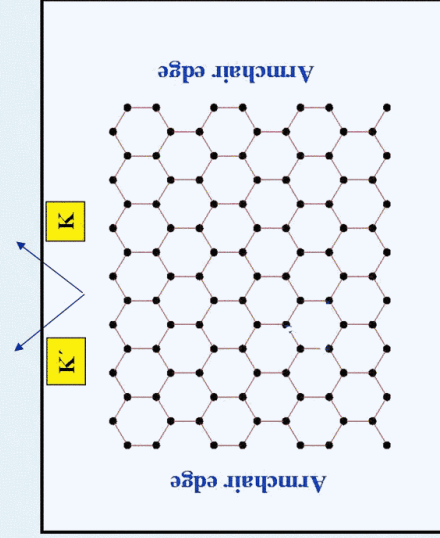


**K'-valley: Dispersionless Edge States**

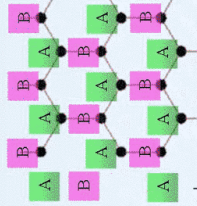
- Equations satisfied for  $\varphi'_B=0$  and  $\varphi'_A$  a LLL state, even when guiding center is off edge of system  $\Rightarrow \varphi'_A$  the tail of a Gaussian, and  $\varepsilon = 0$
- These states carry no current!

$\Rightarrow n=0$  Hall conductance is half as large as steps for larger  $n$

(2) Tight-binding results, armchair edge



Two sets of edge states for  $n>0$ , one for  $n=0$ .



Boundary conditions:  
 $\phi_B(x=0) + \phi'_B(x=0) = 0$   
 $\phi_A(x=0) + \phi'_A(x=0) = 0$   
 Admixes valleys

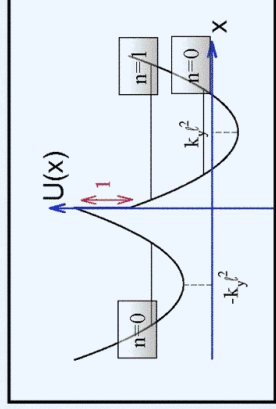
Missing row of atoms with equal number of atoms from both sublattices

$$\varphi_A = b\varphi_B/\varepsilon \Rightarrow \partial_x \varphi_B(x=0) + \partial_x \varphi'_B(x=0) = 0$$

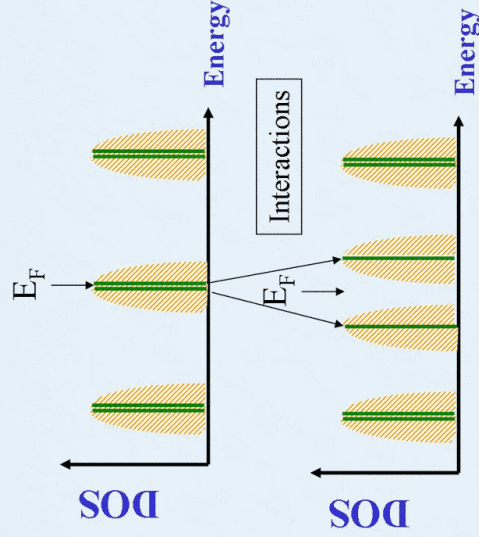
$$\varphi'_A = -b^\dagger \varphi'_B/\varepsilon$$

Trick: define wavefunction for  $-\infty < x < \infty$ :

$$\psi(x) = \varphi_B(x)\theta(x) + \varphi'_B(-x)\theta(-x)$$



### III. Quantum Hall Ferromagnetism and the Graphene Edge



- Exchange tends to force electrons into the same level even when bare splitting between levels is small
- Renormalizes gap to much larger value than expected from non-interacting theory (even if bare gap is zero!)

This does happen in graphene  
(Zhang et al., 2006).

- Plateaus at  $\nu=0, \pm 1$ .
- System is a *pseudospin ferromagnet*.

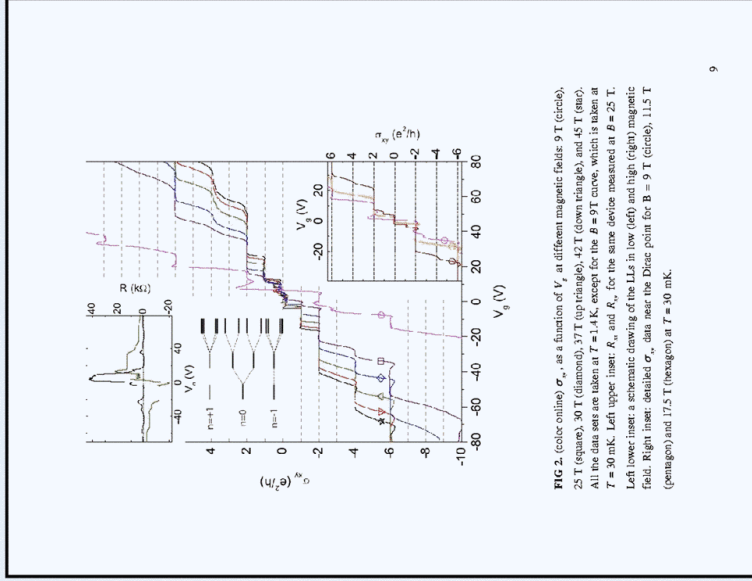
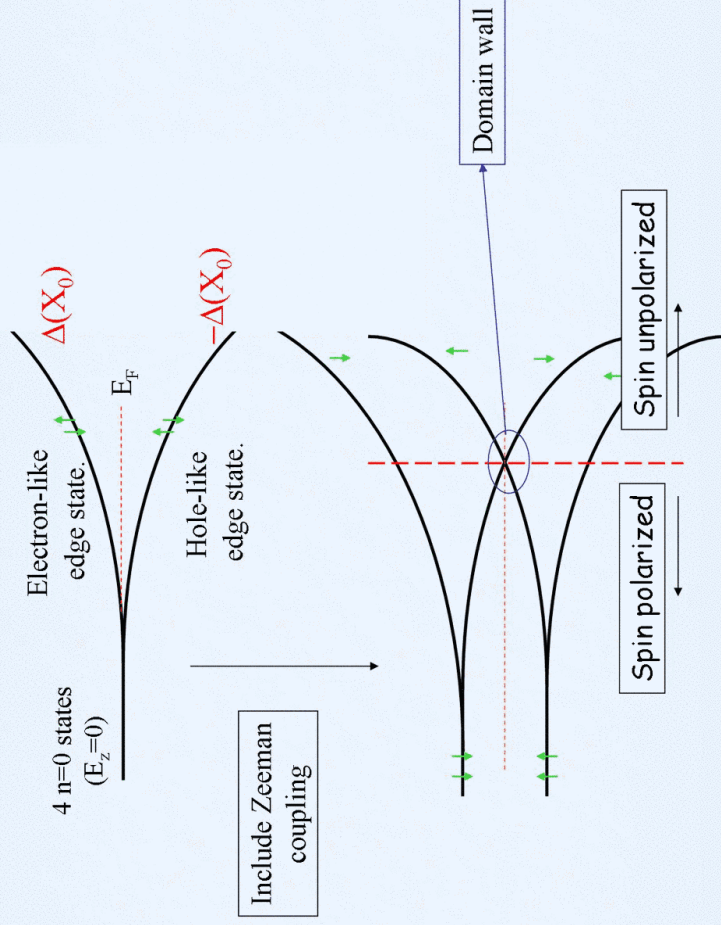


FIG 2. (color online)  $\nu$ , as a function of  $V_g$  at different magnetic fields: 9 T (circle), 25 T (square), 30 T (diamond), 37 T (up triangle), 42 T (down triangle), and 45 T (star). All the data sets are taken at  $T = 1.4$  K, except for the  $B = 9$  T curve, which is taken at  $T = 30$  mK. Left upper inset:  $R_{xx}$  and  $R_{xy}$  for the same device measured at  $B = 25$  T. Left lower inset: a schematic drawing of the LLs in low (left) and high (right) magnetic field. Right inset: detailed  $\nu$  data near the Dirac point for  $B = 9$  T (circle), 17.5 T (pentagon) and 17.5 T (hexagon) at  $T = 30$  mK.

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### Consequences for edge states:





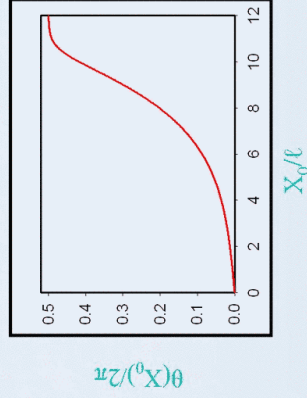
Description of the domain wall:

$$|\Psi\rangle = \prod_{X_0 < L} \left[ \cos \frac{\theta(X_0)}{2} C_{+X_0, \uparrow}^+ + \sin \frac{\theta(X_0)}{2} C_{-X_0, \downarrow}^+ \right] C_{-X_0, \uparrow}^+ |0\rangle$$

$$X_0 \rightarrow -\infty \quad \theta = 0; \quad X_0 \rightarrow L \quad \theta = \pi$$

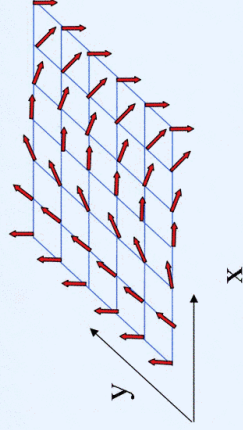
$$E = \pi \ell^2 \rho_s \sum_{X_0 < L} \left( \frac{d\theta}{dX_0} \right)^2 + \sum_{X_0 < L} (E_z - \Delta(X_0)) \cos \theta(X_0)$$

Pseudospin stiffness

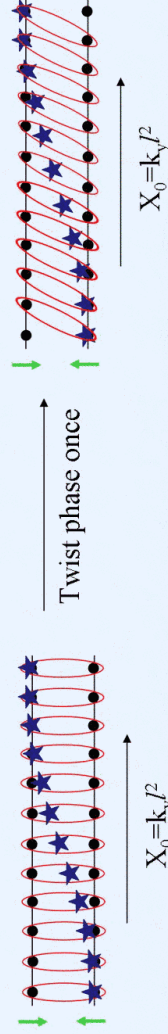


Result of minimizing energy. Width of domain wall set by strength of confinement.

Properties of the domain wall



1. Broken U(1) symmetry  $\Rightarrow$  gapless collective mode
2. Spin-charge coupling  $\Rightarrow$  gapless charged excitations!



★ = weight in w/f

3. Tunneling from STM

tip: power law IV

⇒ not a Fermi liquid!

Power law exponent a function of confinement potential

4. Tunneling from a bulk lead:

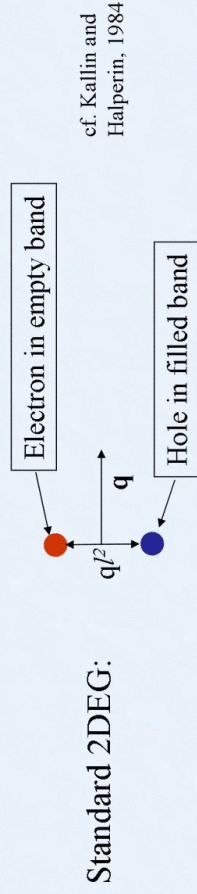
possibility of a quantum phase transition (into 3D metal).

$\rho = U(1)$  spin stiffness  
 $\Gamma \sim$  confinement potential

$$\frac{dt^2}{dl} = -(\kappa - 2)t^2 \quad \kappa = (x + 1/x)/2 \quad x = 4\pi\sqrt{\rho/\Gamma}$$

**IV. Inter-Landau Level Excitations (Magnetoplasmons)**

Low-lying excited states = particle-hole pairs



- Measurable in cyclotron resonance, inelastic light scattering.
- This picture is largely the same for graphene, just need to be careful about spinor structure of particle and hole states.

Two-Body Problem

$$H_0 = \underbrace{(p_1 - A_1) \cdot \sigma \otimes 1 + 1 \otimes (p_2 + A_2) \cdot \sigma}_{\text{Electron}} \underbrace{\quad}_{\text{Hole}} \quad (\hbar\omega_c = l=1)$$

To diagonalize ( $\mathbf{A} = -B\mathbf{y}\mathbf{x}$ ):

1. Adopt center and relative coordinate  $\mathbf{R} = (\mathbf{r}_1 + \mathbf{r}_2)/2$ ,  $\mathbf{r} = \mathbf{r}_1 - \mathbf{r}_2$
2. Apply unitary transformation  $H'_0 = U^\dagger H_0 U$  with

$$U = e^{i\vec{p} \cdot (\hat{z} \times \vec{P})} e^{-ixy} \quad \vec{P} = \text{center of mass momentum}$$

$$\rightarrow H'_0 = \sqrt{2} \left[ -\mathbf{1} \otimes \begin{pmatrix} 0 & c_- \\ c_+^\dagger & 0 \end{pmatrix} + \begin{pmatrix} 0 & c_+^\dagger \\ c_+ & 0 \end{pmatrix} \right] \otimes \mathbf{1}$$

with

$$\begin{aligned} c_+^\dagger &= \frac{i}{\sqrt{2}} (-2\partial_z + \bar{z}/2) \\ c_-^\dagger &= \frac{i}{\sqrt{2}} (-2\partial_{\bar{z}} + z/2) \end{aligned} \quad z = x + iy$$

Wavefunctions constructed from:

$$\varphi_{n_+, n_-}(z, \bar{z}) = \frac{(c_+^\dagger)^{n_+} (c_-^\dagger)^{n_-}}{\sqrt{n_+!} \sqrt{n_-!}} \varphi_{0,0}(z, \bar{z})$$

with

$$\varphi_{0,0}(z, \bar{z}) = (2\pi)^{-1/2} e^{-\frac{1}{4}z\bar{z}}$$

Wavefunctions are 4-vectors  $|n_+, n_-\rangle$  constructed from  $\varphi_{n_+, n_-}$  with energies

$$E = \sqrt{2} [s_+ \sqrt{|n_+|} - s_- \sqrt{|n_-|}]$$

$$s_+ = 1, \quad s_- = -1$$

Electron

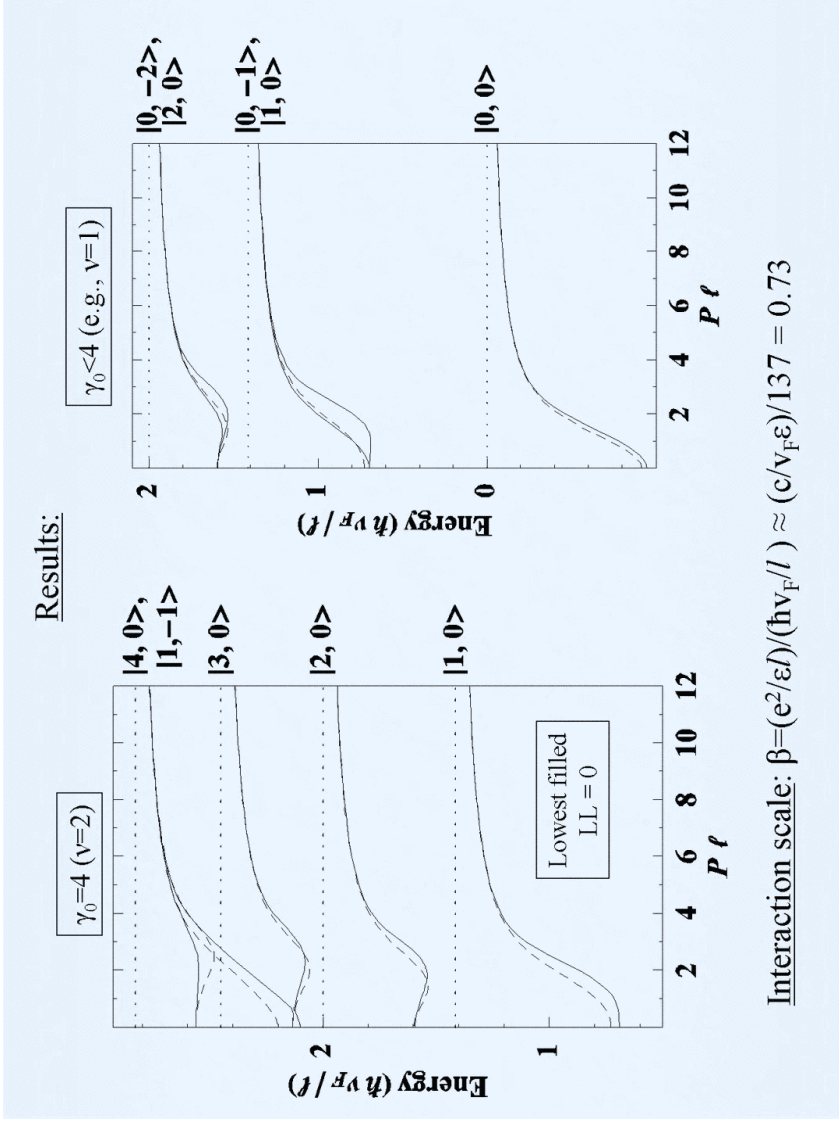
Hole

3. Apply unitary transformation to interaction  $H'_1$ :

$$H'_1 = -e^2 / (\epsilon |\mathbf{r} - \hat{\mathbf{z}} \times \mathbf{P}|) \mathbf{1} \otimes \mathbf{1}$$

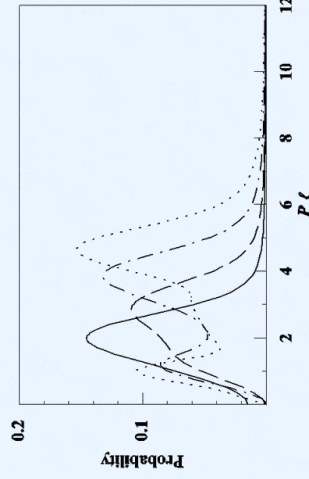
4. Compute eigenvalues of  $\langle n'_+, n'_- | H'_0 + H'_1 | n_+, n_- \rangle$

$\Rightarrow$  two-body eigenenergies with fixed  $\mathbf{P}$



Comments:

1. Negative energies because we have not included loss of exchange self-energy  $\Rightarrow$  many-body approach needed
2. Landau level mixing relatively small



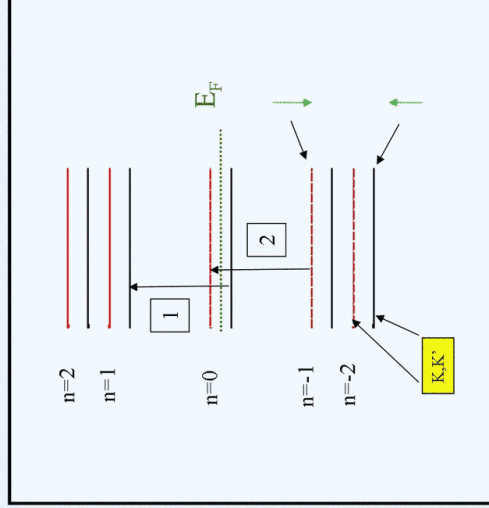
Note however for  $\beta \approx 1$ , LL mixing becomes much more pronounced  $\Rightarrow$  system on cusp between weakly and strongly interacting

Many-Body Particle-Hole Approach

$$|q\rangle = \rho_{\tau,\sigma,n,\tau',\sigma',n'}(\mathbf{q})|GS\rangle$$

$$\rho_{\tau,\sigma,n,\tau',\sigma',n'}(\mathbf{q}) = \frac{1}{N_\phi} \sum_X e^{-\frac{i}{2}q_x(2X+q_y)} C_{\tau,\sigma,n,X}^{\tau',\sigma',n'} C_{\tau,\sigma,n,X}^{\tau',\sigma',n'} + q_y$$

Must watch out for degeneracies:



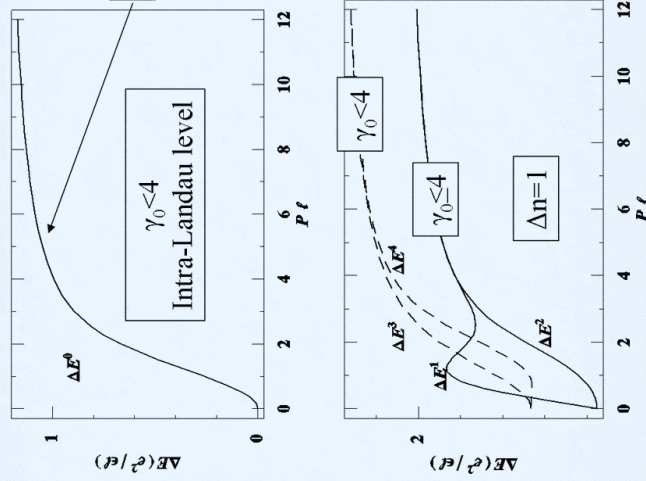
$$|q\rangle = [c_1\rho_1(\mathbf{q}) + c_2\rho_2(\mathbf{q})]|GS\rangle$$

$$|c_1|^2 + |c_2|^2 = 1$$

$$\Delta E = \langle \mathbf{q} | H | \mathbf{q} \rangle - E_0$$

- Minimize with respect to \$c\_1\$ and \$c\_2\$
- Excitations characterized by \$\Delta S\_z\$ and \$\Delta \tau\_z\$

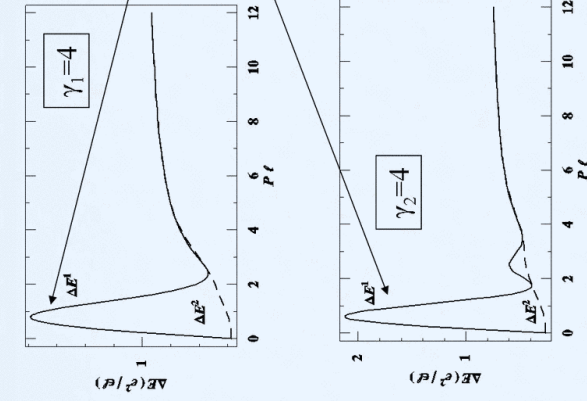
Results: N=0



Two-body result (up to constant)

Comments:

1. Change in kinetic energy and Zeeman energy must be added in
2. Gapless excitations for \$\nu=-1, 1\$
3. Excitation spectra *identical* for \$\nu=-1, 1\$: particle-hole symmetry
4. Electron-electron interaction contribution considerable



Dashed lines equivalent to two-body result.

Very large many-body correction!

- Minima/maxima may be visible in inelastic light scattering or microwave absorption.

## Summary

- Graphene in quantum Hall regime supports unusual edge states
- Zigzag edge: current-carrying and dispersionless edge states in LLL
- Armchair edge: admixing of two valleys
- Clean system is likely a quantum Hall ferromagnet.
- Armchair edges: oppositely dispersing spin up and down bands  
 ⇒ domain wall
- Domain wall supports gapless collective excitations, and gapless charged excitations through pseudospin texture.
- Domain wall supports power law IV (Luttinger liquid).
- Domain wall may undergo quantum phase transition when coupled to a bulk lead.
- Collective inter-Landau level excitations = excitons
- Many-body corrections split and distort dispersions found in two-body problem